# 2N3117

# NPN SILICON TRANSISTOR



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# DESCRIPTION:

The CENTRAL SEMICONDUCTOR 2N3117 type is an NPN silicon transistor designed for general purpose amplifier applications.

MARKING: FULL PART NUMBER



| MAXIMUM RATINGS: (T <sub>A</sub> =25°C)                                   | SYMBOL             |             | UNITS |  |  |  |  |
|---|--------------------|-------------|-------|--|--|--|--|
| Collector-Base Voltage  | $V_{CBO}$          | 60          | V     |  |  |  |  |
| Collector-Emitter Voltage   | $V_{CEO}$          | 60          | V     |  |  |  |  |
| Emitter-Base Voltage  | $V_{EBO}$          | 6.0         | V     |  |  |  |  |
| Continuous Collector Current  | IC                 | 50          | mA    |  |  |  |  |
| Power Dissipation   | $P_{D}$            | 360         | mW    |  |  |  |  |
| Operating and Storage Junction Temperature                                | $T_{J_{I}}T_{stg}$ | -65 to +200 | °C    |  |  |  |  |
| ELECTRICAL CHARACTERISTICS: (T <sub>A</sub> =25°C unless otherwise noted) |                    |             |       |  |  |  |  |
| SYMBOL TEST CONDITIONS  | MIN                | MAX         | UNITS |  |  |  |  |
| I <sub>CBO</sub> V <sub>CB</sub> =45V                                     |                    | 10          | nA    |  |  |  |  |
| I <sub>CBO</sub> V <sub>CB</sub> =45V, T <sub>A</sub> =150°C              |                    | 10          | μA    |  |  |  |  |
| I <sub>EBO</sub> V <sub>EB</sub> =5.0V                                    |                    | 10          | nA    |  |  |  |  |

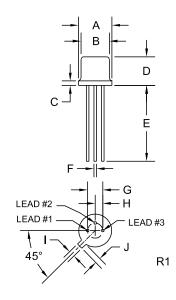
| SYMBOL               | TEST CONDITIONS                                   | MIN    | MAX  | UNITS |
|----------------------|---|--------|------|-------|
| СВО                  | V <sub>CB</sub> =45V                              |        | 10   | nA    |
| Ісво                 | V <sub>CB</sub> =45V, T <sub>A</sub> =150°C       |        | 10   | μA    |
| IEBO                 | V <sub>EB</sub> =5.0V                             |        | 10   | nA    |
| BV <sub>CBO</sub>    | I <sub>C</sub> =10μA                              | 60     |      | V     |
| <b>BV</b> CEO        | I <sub>C</sub> =10mA                              | 60     |      | V     |
| BVEBO                | I <sub>E</sub> =10μA                              | 6.0    |      | V     |
| V <sub>CE(SAT)</sub> | I <sub>C</sub> =1.0mA, I <sub>B</sub> =100μA      |        | 0.35 | V     |
| V <sub>BE(ON)</sub>  | $V_{CE}$ =5.0V, $I_{C}$ =100 $\mu$ A              |        | 0.7  | V     |
| h <sub>FE</sub>      | $V_{CE}$ =5.0V, $I_{C}$ =1.0 $\mu$ A              | 100    |      |       |
| h <sub>FE</sub>      | $V_{CE}$ =5.0V, $I_{C}$ =10 $\mu$ A               | 250    | 500  |       |
| h <sub>FE</sub>      | $V_{CE}$ =5.0V, $I_{C}$ =10 $\mu$ A, $T_{A}$ =-55 | °C 50  |      |       |
| hFE                  | $V_{CE}$ =5.0V, $I_{C}$ =100 $\mu$ A              | 300    |      |       |
| hFE                  | $V_{CE}$ =5.0V, $I_{C}$ =1.0mA                    | 400    |      |       |
| h <sub>fe</sub>      | $V_{CE}$ =5.0V, $I_{C}$ =0.5mA, f=30M             | Hz 2.0 |      |       |
| C <sub>ob</sub>      | $V_{CB}$ =5.0V, $I_{E}$ =0                        |        | 4.5  | pF    |
| C <sub>ib</sub>      | $V_{EB}$ =0.5V, $I_{C}$ =0                        |        | 6.0  | pF    |
| NF                   | $V_{CE}$ =5.0V, $I_{C}$ =5.0 $\mu$ A, f=10kH      | lz     |      |       |
|                      | BW=1.0kHz, $R_S$ =50k $\Omega$                    |        | 1.0  | dB    |

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## **TO-18 CASE - MECHANICAL OUTLINE**



| DIMENSIONS |        |       |             |      |  |  |
|------------|--------|-------|-------------|------|--|--|
|            | INCHES |       | MILLIMETERS |      |  |  |
| SYMBOL     | MIN    | MAX   | MIN         | MAX  |  |  |
| A (DIA)    | 0.209  | 0.230 | 5.31        | 5.84 |  |  |
| B (DIA)    | 0.178  | 0.195 | 4.52        | 4.95 |  |  |
| С          | -      | 0.030 | -           | 0.76 |  |  |
| D          | 0.170  | 0.210 | 4.32        | 5.33 |  |  |
| E          | 0.500  | -     | 12.70       | -    |  |  |
| F (DIA)    | 0.016  | 0.019 | 0.41        | 0.48 |  |  |
| G (DIA)    | 0.100  |       | 2.54        |      |  |  |
| Н          | 0.050  |       | 1.27        |      |  |  |
| I          | 0.036  | 0.046 | 0.91        | 1.17 |  |  |
| J          | 0.028  | 0.048 | 0.71        | 1.22 |  |  |

TO-18 (REV: R1)

## LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector

## MARKING:

**FULL PART NUMBER** 

## **OUTSTANDING SUPPORT AND SUPERIOR SERVICES**



#### PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

#### **DESIGNER SUPPORT/SERVICES**

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2<sup>nd</sup> day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- Custom product and package development

#### REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

#### **CONTACT US**

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